

2SA1550

Silicon PNP triple diffusion planar type

For power switching

Features

- High forward current transfer ratio h_{FE}
- High-speed switching
- High collector to base voltage V_{CBO}
- I type package enabling direct soldering of the radiating fin to the printed circuit board, etc. of small electronic equipment.

Absolute Maximum Ratings ($T_C=25^\circ\text{C}$)

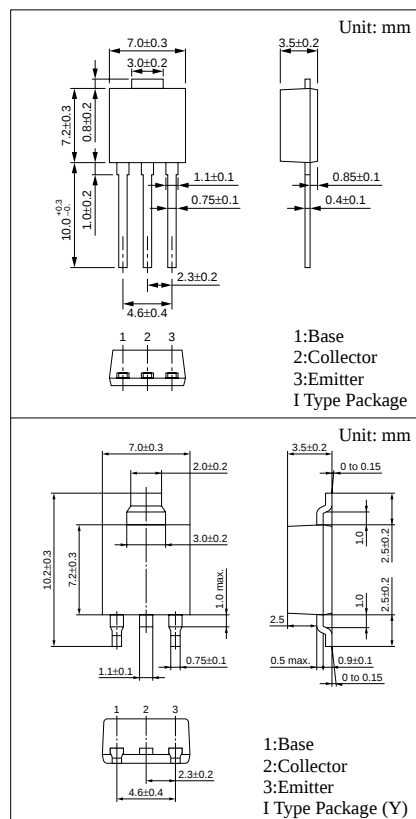
Parameter	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	-400	V
Collector to emitter voltage	V_{CEO}	-400	V
Emitter to base voltage	V_{EBO}	-7	V
Peak collector current	I_{CP}	-1.0	A
Collector current	I_C	-0.5	A
Collector power dissipation	P_C	15	W
		1.3	
Junction temperature	T_j	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

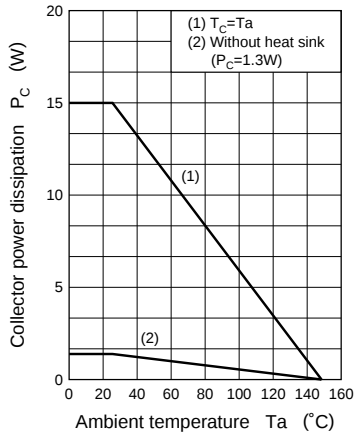
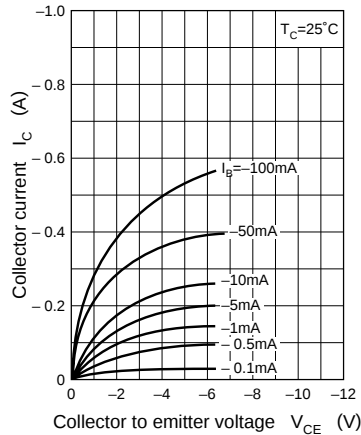
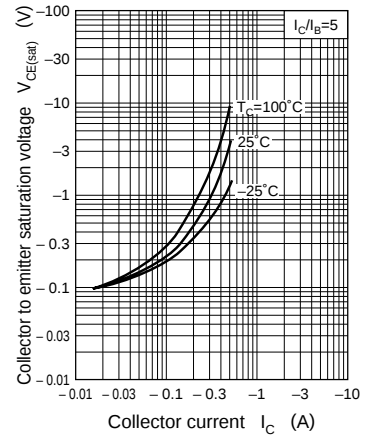
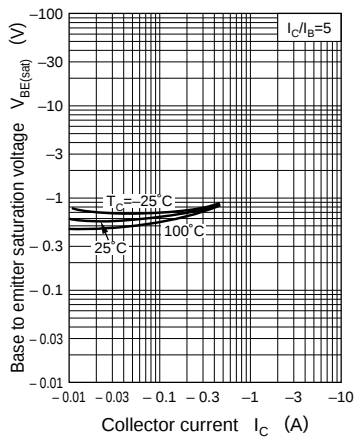
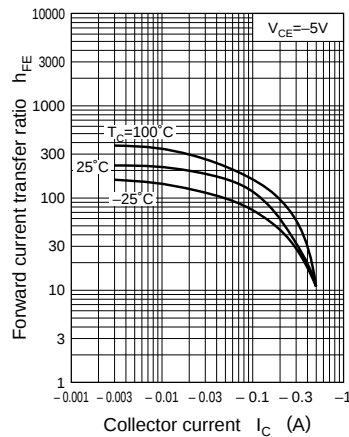
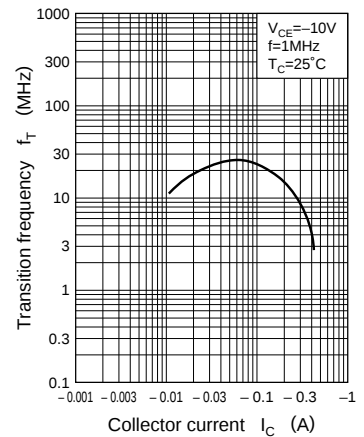
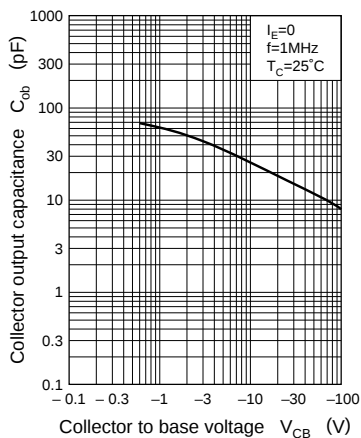
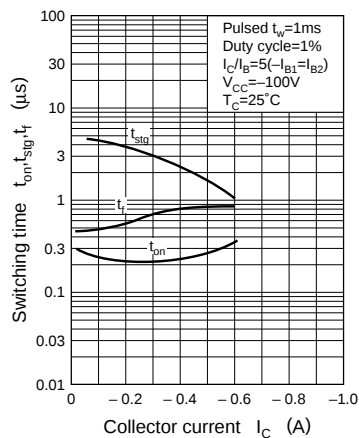
Electrical Characteristics ($T_C=25^\circ\text{C}$)

Parameter	Symbol	Conditions	min	typ	max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = -400\text{V}$, $I_E = 0$			-100	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = -7\text{V}$, $I_C = 0$			-100	μA
Collector to emitter voltage	V_{CEO}	$I_C = -10\text{mA}$, $I_B = 0$	-400			V
Forward current transfer ratio	h_{FE1}^*	$V_{CE} = -5\text{V}$, $I_C = -50\text{mA}$	80		280	
	h_{FE2}	$V_{CE} = -5\text{V}$, $I_C = -300\text{mA}$	10			
Collector to emitter saturation voltage	$V_{CE(sat)}$	$I_C = -200\text{mA}$, $I_B = -40\text{mA}$			-1.5	V
Base to emitter saturation voltage	$V_{BE(sat)}$	$I_C = -200\text{mA}$, $I_B = -40\text{mA}$			-1.5	V
Transition frequency	f_T	$V_{CE} = -10\text{V}$, $I_C = -100\text{mA}$, $f = 1\text{MHz}$		20		MHz
Turn-on time	t_{on}	$I_{B1} = -60\text{mA}$, $I_{B2} = 60\text{mA}$, $V_{CC} = -200\text{V}$		0.25		μs
Storage time	t_{stg}			2.0		μs
Fall time	t_f			0.5		μs

* h_{FE1} Rank classification

Rank	Q	P
h_{FE1}	80 to 160	130 to 280



$P_C - T_a$  $I_C - V_{CE}$  $V_{CE(sat)} - I_C$  $V_{BE(sat)} - I_C$  $h_{FE} - I_C$  $f_T - I_C$  $C_{ob} - V_{CB}$  $t_{on}, t_{stg}, t_f - I_C$ 

Area of safe operation (ASO)

